

# **Excellent Integrated System Limited**

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Vishay Semiconductor/Diodes Division HFA30PB120

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite



Datasheet of HFA30PB120 - DIODE GEN PURP 1.2KV 30A TO247AC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



### HFA30PB120

Vishay High Power Products

## HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 30 A

### FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Guaranteed avalanche
- Specified at operating conditions
- · Designed and qualified for industrial level

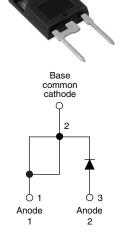
#### BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

#### DESCRIPTION

HFA30PB120 is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 30 A continuous current, the HFA30PB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BBM</sub>) and does not exhibit any tendency to "snap-off" during the  $t_b$  portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA30PB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V <sub>R</sub>		1200	V	
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	30		
Single pulse forward current	I <sub>FSM</sub>		120	А	
Maximum repetitive forward current	I <sub>FRM</sub>		90		
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	350	W	
Maximum power dissipation		T <sub>C</sub> = 100 °C	140	vv	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C	



#### TO-247AC modified

PRODUCT SUMMARY				
V <sub>R</sub>	1200 V			
V <sub>F</sub> at 30 A at 25 °C	4.1 V			
I <sub>F(AV)</sub>	30 A			
t <sub>rr</sub> (typical)	47 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub> (typical)	120 nC			
dI <sub>(rec)M</sub> /dt (typical) at 125 °C	240 A/µs			
I <sub>RRM</sub> (typical)	4.7 A			

<sup>1</sup> 



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ELECTRICAL SPECIFICATIONS (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		1200	-	-	
		I <sub>F</sub> = 30 A		-	2.4	4.1	v
Maximum forward voltage V <sub>FM</sub>	V <sub>FM</sub>	I <sub>F</sub> = 60 A	See fig. 1	-	3.1	5.7	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C		-	2.3	4.0	
Maximum reverse		V <sub>R</sub> = V <sub>R</sub> rated	Coofig 0	-	1.3	40	
leakage current	I <sub>RM</sub>	$T_J$ = 125 °C, $V_R$ = 0.8 x $V_R$ rated	srated See fig. 2		1.1	4000	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	50	75	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0 - r		nH			

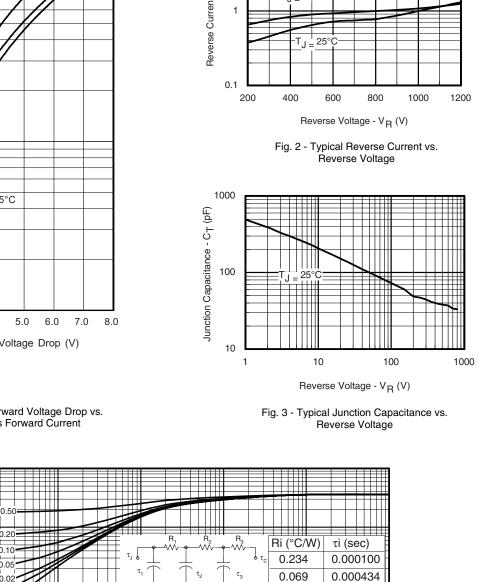
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	47	-	
Reverse recovery time See fig. 5, 10	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	110	170	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	170	260	
Peak recovery current See fig. 6	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	10	15	A
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	16	24	
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	650	980	nC
See fig. 7	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	1540	2310	
Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	270	-	A/µs
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	240	-	Ανμs

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.36	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	80	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.50	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style TO-247AC modified (JEDEC)	HFA30PB120			



**VISHAY HEXFRED<sup>®</sup>** Vishay High Power Products Ultrafast Soft Recovery Diode, 30 A 10 Reverse Current - I R (µA) 150 100 \_ 125°C 1 Ti = 175°C ТJ . 25 I<sub>F</sub>, Instantaneous Forward Current (A) 0.1 200 400 10 1000 Tj = 125°C Junction Capacitance -  $C_{T}$  (pF) Γj = 25<sup>°</sup>C 100 25 1 1.0 2.0 8.0 3.0 4.0 5.0 6.0 7.0 V<sub>F</sub>, Forward Voltage Drop (V) 10 10 1 Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current Thermal Response ( Z thJC ) 0.1 R<sub>0</sub> 20 R R Ri (°C/W) 0.234 0.05

**HFA30PB120** 



0.056

otes:

1. Duty Factor D = t1/t2

0.002202

0.1

0.01

0.001

SINGLE PULSE

(THERMAL RESPONSE



Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of HFA30PB120 - DIODE GEN PURP 1.2KV 30A TO247AC

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**HEXFRED<sup>®</sup>** 

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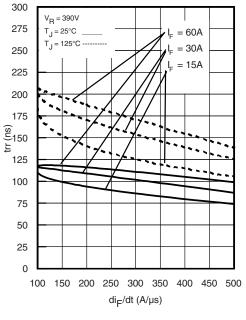


Fig. 5 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt (Per Leg)

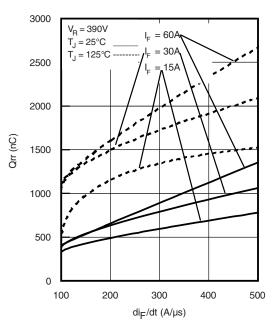


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt (Per Leg)

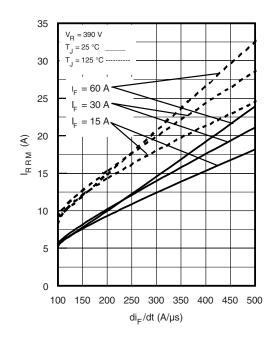


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt (Per Leg)

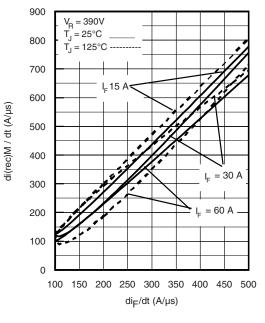
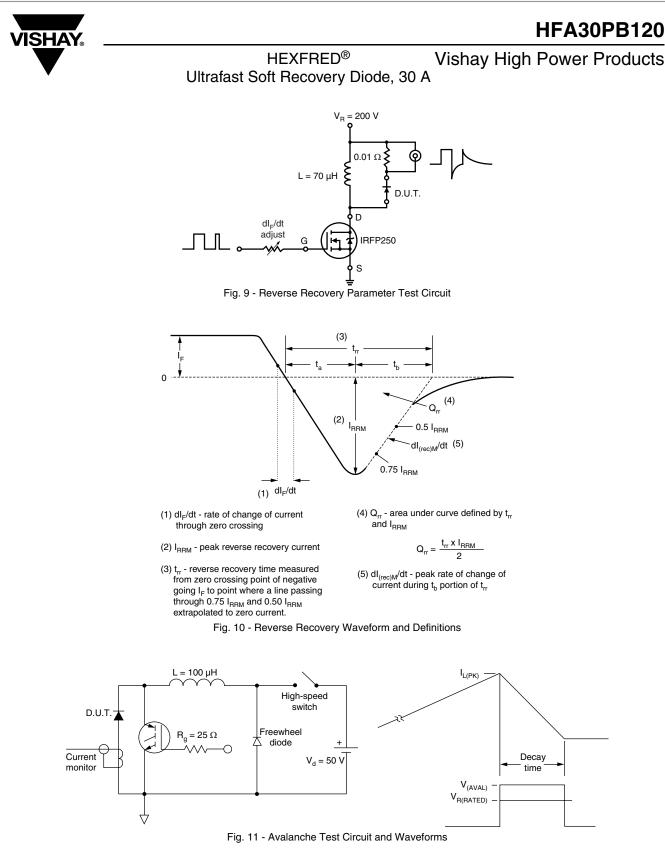


Fig. 8 - Typical dl<sub>(rec)M</sub>/dt vs. dl<sub>F</sub>/dt (Per Leg)







### HFA30PB120

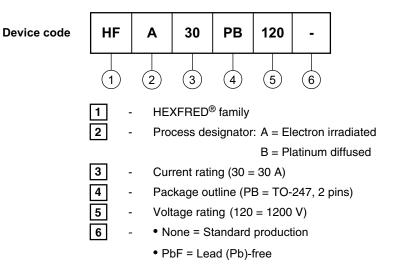
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HEXFRED<sup>®</sup>



Ultrafast Soft Recovery Diode, 30 A

### **ORDERING INFORMATION TABLE**



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			
SPICE model	http://www.vishay.com/doc?95358			





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